(FILE 'HOME' ENTERED AT 11:52:42 ON 14 NOV 2001)

	FILE 'CAPLUS	S' ENTERED AT 11:52:49 ON 14 NOV 2001
L1	1394 \$	G (ION OR HE OE HE! OR AR OR NE OR NE! OR ARGON OR NEON OR HELI
L2	1430 \$	G (ION OR HE OR HE! OR AR OR NE OR NE! OR ARGON OR NEON OR HELI
L3	14177 \$	(ION OR HE OR HE! OR AR OR NE OR NE! OR ARGON OR NEON OR HELI
L4		((ION OR HE OR HE! OR AR OR NE OR NE! OR ARGON OR NEON OR HEL
L5	544372	G (PATTERN OR PATTERNING OR MASK OR MASKING OR MASKED)
L6	373 \$	S L3 AND L5
L7	64 \$	S L1 AND L5
L8		S L4 AND L5
L9		S L6 NOT (WIND OR AIR OR ATMOSPHER? OR METEOR?)
L10	52 \$	S L7 NOT (WIND OR AIR OR ATMOSPHER? OR METEOR?)
L11	9031	G (ION OR HE OR AR OR NE OR ARGON OR NEON OR HELIUM) (15A) (MIXIN
L12	29 \$	S L11(P)(MASK? OR PHOTOMASK?)
•		

=> log y COST IN U.S. DOLLARS	SINCE FILE ENTRY 426.33	TOTAL SESSION 426.48
FULL ESTIMATED COST	•==	
DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)	SINCE FILE ENTRY	TOTAL
CA SUBSCRIBER PRICE	-70.56	-70.56

STN INTERNATIONAL LOGOFF AT 12:19:44 ON 14 NOV 2001

(FILE 'HOME' ENTERED AT 10:08:33 ON 14 NOV 2001)

FILE 'CAPLUS' ENTERED AT 10:08:45 ON 14 NOV 2001

59454 S (HE OR HE! OR HELIUM OR NE OR NEON OR NE! OR AR OR ARGON OR A L1

1756 S L1(P)(MASK? OR PHOTOMASK? OR PATTERN?)

L2 139 S L2 AND (MULTILAYER? OR ((LAMINATED OR MULTI OR MULTIPLE OR AL L3

=> log y

TOTAL SINCE FILE COST IN U.S. DOLLARS SESSION ENTRY 380.51 380.36

FULL ESTIMATED COST

TOTAL SINCE FILE DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS) SESSION ENTRY

-81.73 -81.73 CA SUBSCRIBER PRICE

STN INTERNATIONAL LOGOFF AT 10:17:29 ON 14 NOV 2001

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L13
     ANSWER- 14 OF 22 CAPLUS COPYRIGHT 2001 ACS
AN
     1989:146339 CAPLUS
DN ~
     110:146339
ΤI
     Direct formation of ferromagnetic manganese-bismuth layers with
     perpendicular magnetic anisotropy by ion-beam mixing
ΑU
     Kido, Yoshiaki; Suzuki, Motofumi
CS
     Toyota Cent. Res. and Dev. Lab. Inc., Nagakute, 480-11, Japan
SO
     Mater. Lett. (1988), 7(5-6), 219-23
     CODEN: MLETDJ; ISSN: 0167-577X
DT
     Journal
     English
LΑ
CC
     77-1 (Magnetic Phenomena)
     Section cross-reference(s): 56
     Multilayers of Mn/Bi deposited on glass, Al, and Si substrates
AB
     were irradiated with 400 keV Xe+ at 80-550 K. Irradn. from room
     temp. up to 500 K leads to the formation of ferromagnetic Mn-Bi
     layers with the hexagonal c-axis oriented perpendicular to the substrate
     surface. Strong perpendicular magnetic anisotropy is obsd. for
     the above specimens using x-ray diffraction and a vibrating sample
     magnetometer. Quenched metastable phases with ferromagnetism are
     not obtained for the Mn(25-50 at.%)/Bi multilayers irradiated
     with 400 keV Xe+ at 80-550 K. The dependence is discussed of the
     magnetic properties of the ion-mixed layers on
     irradn. temp., ion dose, and substrate species.
ST
     xenon ion beam mixing manganese bismuth; multilayer manganese
     bismuth mixing; ferromagnetism manganese bismuth mixing; anisotropy
     magnetic manganese bismuth mixing
IT
     Glass, oxide
     RL: USES (Uses)
        (ion mixing of manganese-bismuth multilayers on)
TΨ
     Coercive force, magnetic
       Magnetic anisotropy
       Magnetic hysteresis
       Magnetic induction and Magnetization
        (of bismuth-manganese multilayers after xenon-ion-induced
        mixing)
     12626-89-0P, Manganese silicide
IT
     RL: FORM (Formation, nonpreparative); PREP (Preparation)
        (formation of, by ion mixing of manganese-bismuth
       multilayers on silicon)
                         119675-63-7P
IT
     12010-50-3P, BiMn
                                        119675-64-8P, Bismuth 50, manganese 50
     (atomic)
     RL: FORM (Formation, nonpreparative); PREP (Preparation)
        (formation of, by ion-beam mixing of
       manganese-bismuth multilayers)
IT
     7429-90-5, Aluminum, uses and miscellaneous
                                                   7440-21-3, Silicon, uses and
    miscellaneous
    RL: USES (Uses)
        (ion mixing of manganese-bismuth multilayers on)
ΙT
    7439-96-5, Manganese, uses and miscellaneous
    RL: USES (Uses)
        (mixing of bismuth layers with, by xenon ion implantation)
    7440-69-9, Bismuth, uses and miscellaneous
TT
    RL: USES (Uses)
        (mixing of layers of manganese with, by xenon ion implantation)
IT
    24203-25-6, Xenon(1+), uses and miscellaneous
    RL: USES (Uses)
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(mixi

- AN . 1987:589130 CAPLUS DN 107:189130 Circuit design and properties of patterned ion ΤI -implanted layers for field access bubble devices ΑU Nelson, T. J.; Muehlner, D. J. CS Bell Commun. Res., Murray Hill, NJ, 07974, USA Magn. Bubbles (1986), 215-90. Editor(s): Jouve, H. Publisher: Academic, SO London, UK. CODEN: 56CWAD DT Conference; General Review LΑ English CC 77-0 (Magnetic Phenomena) AΒ A review with 75 refs. on the prepn. of magnetic recording disks by ion implantation of ferrite garnets. ST review recording disk implantation ferrite garnet ΙT Ion beams, chemical and physical effects (implantation from, into ferrite garnets in magnetic recording disk fabrication) ΙT Ferrite substances RL: PRP (Properties) (garnets, magnetic recording disk fabrication by ion implantation into) ΙT

ANSWER 48 OF 153 CAPLUS COPYRIGHT 2001 ACS

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